

Axial lead diode

Fast silicon rectifier
diodes

BA 157...BA 159

Forward Current: 1 A

Reverse Voltage: 400 to 1000 V

Features

- Max. solder temperature: 260°C
- Plastic material has UL classification 94V-0

Mechanical Data

- Plastic case DO-41 / DO-204AL
- Weight approx.: 0.4 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 5000 pieces per ammo

1) Valid, if leads are kept at ambient temperature at a distance of 10 mm from case

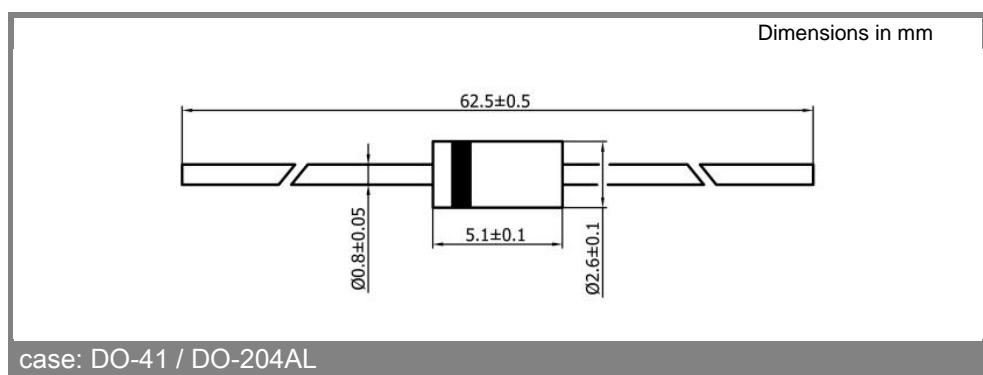
2) $I_F = 1 \text{ A}$, $T_j = 25^\circ\text{C}$

3) $T_A = 25^\circ\text{C}$

Type	Repetitive peak reverse voltage V_{RRM} V	Surge peak reverse voltage V_{RSM} V	Max. reverse recovery time $I_F = 0,5 \text{ A}$ $I_R = 1 \text{ A}$ $I_{RR} = 0,25 \text{ A}$ t_{rr} ns	Max. forward voltage $V_F^{(2)}$
BA 157	400	400	300	1,3
BA 158	600	600	300	1,3
BA 159	1000	1000	300	1,3

Absolute Maximum Ratings		$T_c = 25^\circ\text{C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
I_{FAV}	Max. averaged fwd. current, R-load, $T_A = 50^\circ\text{C}$ ¹⁾	1	A
I_{FRM}	Repetitive peak forward current $f > 15 \text{ Hz}$ ¹⁾	10	A
I_{FSM}	Peak forward surge current 50 Hz half sinus-wave ³⁾	35	A
i^2t	Rating for fusing, $t < 10 \text{ ms}$ ³⁾	6	A ² s
R_{thA}	Max. thermal resistance junction to ambient ¹⁾	45	K/W
R_{thT}	Max. thermal resistance junction to terminals ¹⁾	-	K/W
T_j	Operating junction temperature	-50...+150	°C
T_s	Storage temperature	-50...+175	°C

Characteristics		$T_c = 25^\circ\text{C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
I_R	Maximum leakage current, $T_j = 25^\circ\text{C}$; $V_R = V_{RRM}$	<5	µA
	$T_j = 125^\circ\text{C}$; $V_R = V_{RRM}$	<100	µA
C_J	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF
Q_{rr}	Reverse recovery charge ($U_R = V$; $I_F = A$; $dI_F/dt = A/\text{ms}$)	-	µC
E_{RSM}	Non repetitive peak reverse avalanche energy ($I_R = mA$; $T_j = ^\circ\text{C}$; inductive load switched off)	-	mJ



BA 157...BA 159

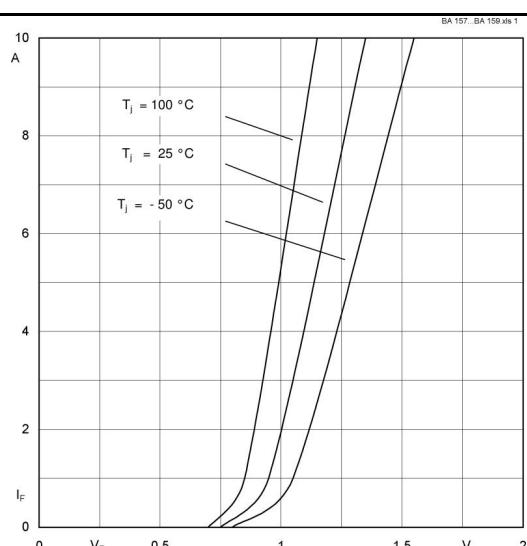


Fig. 1 Forward characteristics (typical values)

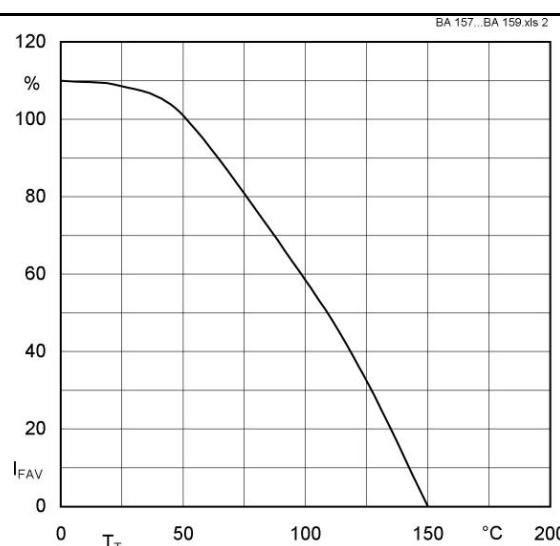


Fig. 2 Rated forward current vs. ambient temperature ¹⁾

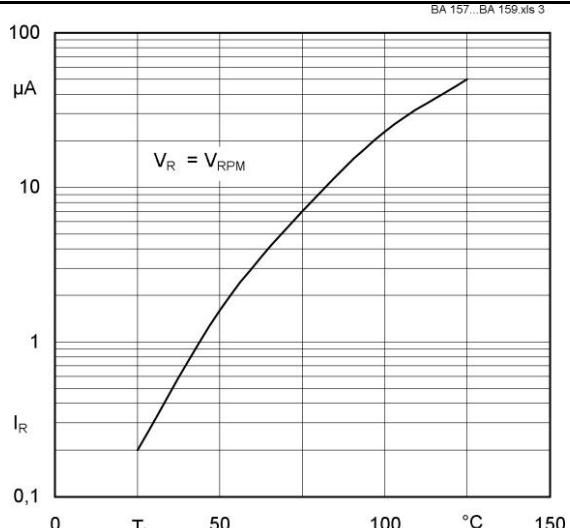


Fig. 3 Leakage current vs. junction temperature

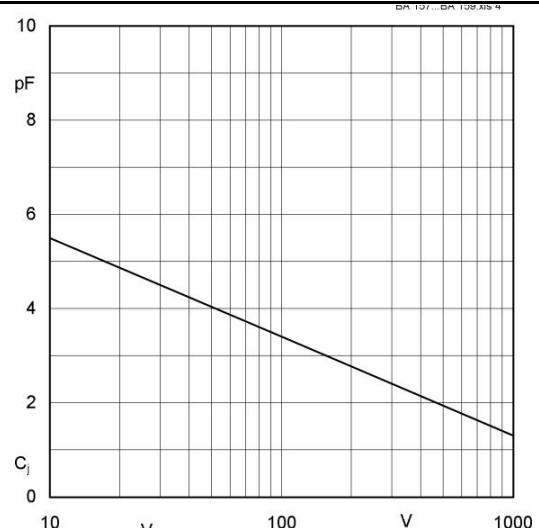


Fig. 4 Typ. junction capacitance vs. reverse voltage